

SMD Type 850nm Infrared Emitter

Features

- Small double-end package
- Viewing Angle = ±60°
- High radiant intensity
- High reliability
- Good spectral matching to Si photo detector
- RoHS compliance

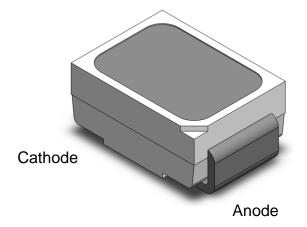
Applications

Infrared sensor

Description

The HIRC3020Q13-B20 is a GaAlAs infrared LED housed in a miniature SMD package. The device has a peak wavelength of 850nm LED spectrally matched with phototransistor or photodiode.

Package Outline



Schematic



HIRC3020Q13-B20 SMD Type 850nm Infrared Emitter

Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
lF	Continuous Forward Current	70	mA	
I _{FP}	Peak Forward Current	0.7	Α	1
VR	Reverse Voltage	5	V	
T _{opr}	Operating Temperature	-40 ~ +85	°С	
T _{stg}	Storage Temperature	-40 ~ +100	°С	
T _{sol}	Soldering Temperature	260	°C	2
P _D	Power Dissipation at(or below) 25°C Free Air Temperature	140	mW	

Electro-Optical Characteristics TA = 25°C (unless otherwise specified)

Optical Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Мах	Units	Notes
	le Radiant Intensity	I _F =20mA	1.5	3.0	-	mW/sr	
ie		I _F =70mA	-	10	-	11100/51	
λр	Peak Wavelength	I _F =20mA	-	850	-	nm	
Δλ	Spectral Bandwidth	I _F =20mA	-	30	-	nm	
θ1/2	Angle of Half Intensity	I _F =20mA	-	±60	-	deg	

Electrical Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward Voltage	I _F =20mA	1.30	1.40	1.7	V	
		I _F =70mA	1.40	1.60	2.0		
I _R	Reverse Current	V _R =5V	-	-	10	μΑ	

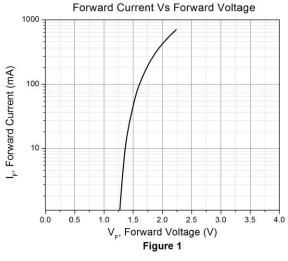
Notes:

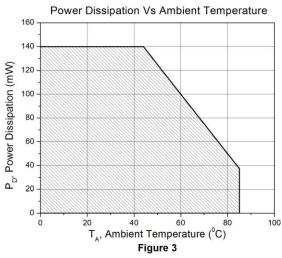
- 1 : I_{FP} Conditions--Pulse Width \leq 100 μ s and Duty \leq 1%.
- 2 : Soldering time≦ 5 seconds.

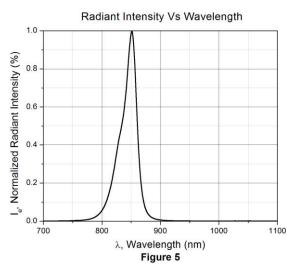


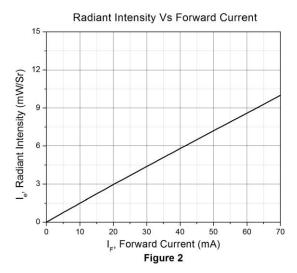
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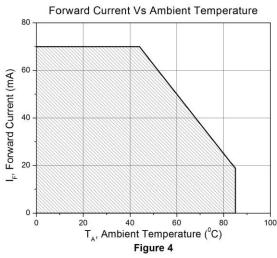
Typical Characteristic Curves







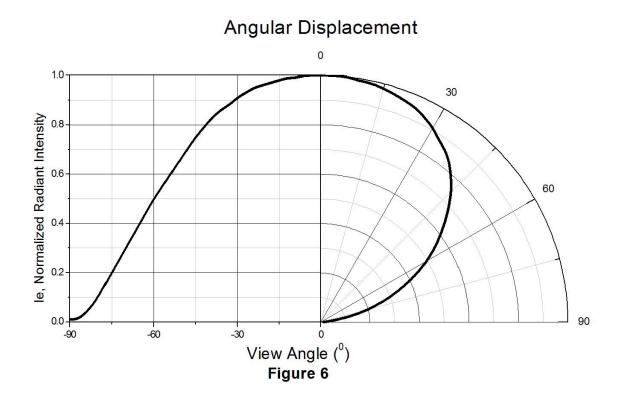






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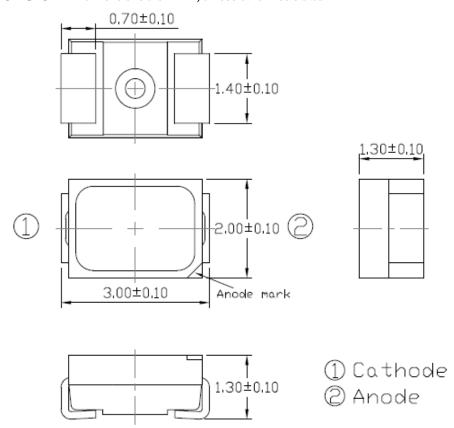
Typical Characteristic Curves



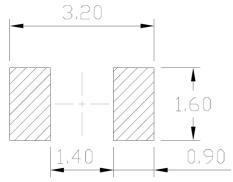


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Package Dimension All dimensions are in mm, unless otherwise stated



Recommended Soldering Mask All dimensions are in mm, unless otherwise stated



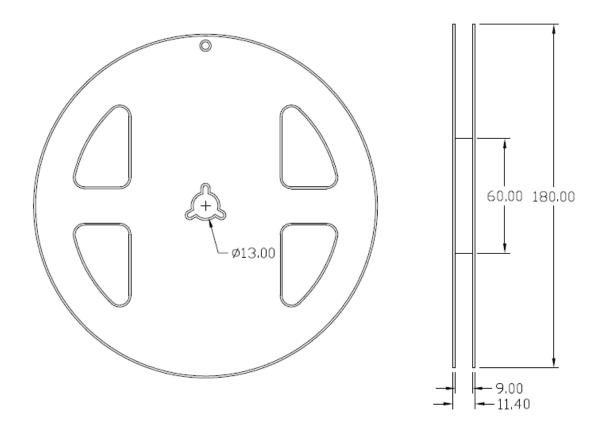
Ordering Information

Part Number	Description	Quantity
HIRC3020Q13-B20	Tape & Reel	2000 pcs

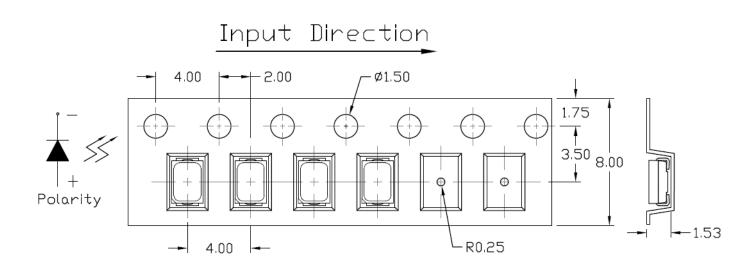


SMD Type 850nm Infrared Emitter

Reel Dimension All dimensions are in mm, unless otherwise stated



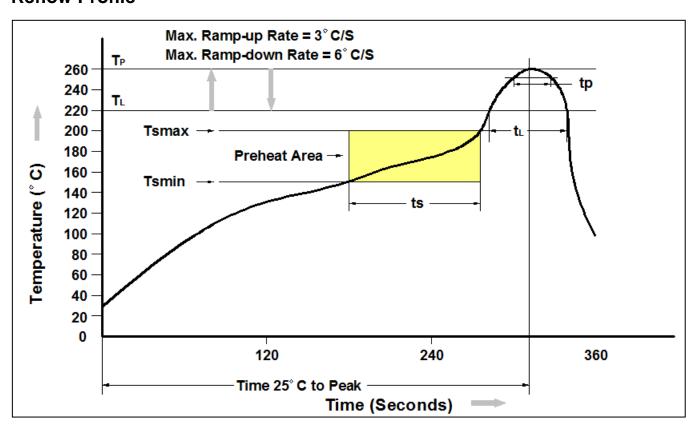
Tape Dimension All dimensions are in mm, unless otherwise stated





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Reflow Profile



Profile Feature	Pb-Free Assembly Profile		
Temperature Min. (Tsmin)	150°C		
Temperature Max. (Tsmax)	200°C		
Time (ts) from (Tsmin to Tsmax)	60-120 seconds		
Ramp-up Rate (t∟ to t⊳)	3°C/second max.		
Liquidous Temperature (T _L)	217°C		
Time (t _L) Maintained Above (T _L)	60 – 150 seconds		
Peak Body Package Temperature	260°C +0°C / -5°C		
Time (t _P) within 5°C of 260°C	30 seconds		
Ramp-down Rate (T _P to T _L)	6°C/second max		
Time 25°C to Peak Temperature	8 minutes max.		



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